CMS2050

MagnetoResistive Current Sensor (I_{PN} = 50 A)

The CMS2000 current sensor family is designed for highly dynamic electronic measurement of DC, AC, pulsed and mixed currents with integrated galvanic isolation. The MagnetoResistivetechnology enables an excellent dynamic response without the hysteresis that is present in iron core based designs.

The CMS2000 product family offers PCB-mountable THT current sensors from 5 A up to 100 A nominal current for industrial applications.

**Product discontinued.
Not to be used for new designs.**

Product Overview

Article description	Package	Delivery Type
CMS2050-SP3 (discontinued)	THT	Tray
CMS2050-SP7 (discontinued)	THT	Tray
CMS2050-SP10 (discontinued)	THT	Tray

Quick Reference Guide

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{CC}	Supply voltage	±12	±15	-	V
I_{PN}	Primary nominal current (RMS)	-	-	50	A
$I_{PR, SP3, SP10}$	Primary measuring range [1]	-200	-	+200	A
$I_{PR, SP7}$	Primary measuring range [2]	-220	-	+220	A
f_{co}	Frequency bandwidth (-3 dB)	200	300	-	kHz
$\varepsilon_{\Sigma, SP3}$	Accuracy for SP3 [3]	-	-	±0.8	% of I_{PN}
$\varepsilon_{\Sigma, SP7}$	Accuracy for SP7 [3]	-	-	±0.8	% of I_{PN}
$\varepsilon_{\Sigma, SP10}$	Accuracy for SP10 [3]	-	-	±0.5	% of I_{PN}

1) For 3 s in a 60 s interval (RMS ≤ I_{PN}) and V_{CC} = ±15 V.

2) For 20 ms in a 60 s interval (R_{MS} ≤ I_{PN}) and V_{CC} = ±15 V.

3) $\varepsilon_{\Sigma} = \varepsilon_G$ & ε_{lin} with V_{CC} = ±15 V, $I_P = I_{PN}$, T_{amb} = 25 °C.

Qualification Overview

Standard	Name	Status
2002/95/EC	RoHS-conformity	Approved
EN 61800-5-1: 2007	Adjustable speed electrical power drive systems	Approved
DIN EN 50178	Electronic equipment for use in power installations	Approved
UL508 (E251279)	Industrial control equipment	Approved

Features

- Based on the AnisotropicMagnetoResistive (AMR) effect
- Measuring range up to 4 times nominal current
- Galvanic isolation between primary and measurement circuit
- Bipolar 15 V power supply

Advantages

- High signal-to-noise ratio
- Highly dynamic step response
- Negligible hysteresis
- Excellent accuracy
- Low temperature drift
- Small and compact size
- Low primary inductance

Applications

- Solar power converters
- Measurement devices
- AC variable speed drives
- Converters for DC motor drives
- Uninterruptible power supplies
- Switched mode power supplies
- Power supplies for welding applications

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ESD
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Absolute Maximum Ratings Values

In accordance with the absolute maximum rating system (IEC60134).

Symbol	Parameter	Min.	Max.	Unit
V_+	Positive supply voltage	-0.3	+17.0	V
V_-	Negative supply voltage	-17.0	+0.3	V
I_{PM}	Maximum primary current [1)]	-500	+500	A
T_{amb}	Ambient temperature	-25	+85	°C
T_{stg}	Storage temperature	-25	+105	°C
T_B	Busbar temperature	-25	+105	°C

1) For 20 ms in a 20 s interval. (RMS ≤ I_{PN}). For SP7 for 20 µs in a 20 s interval.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

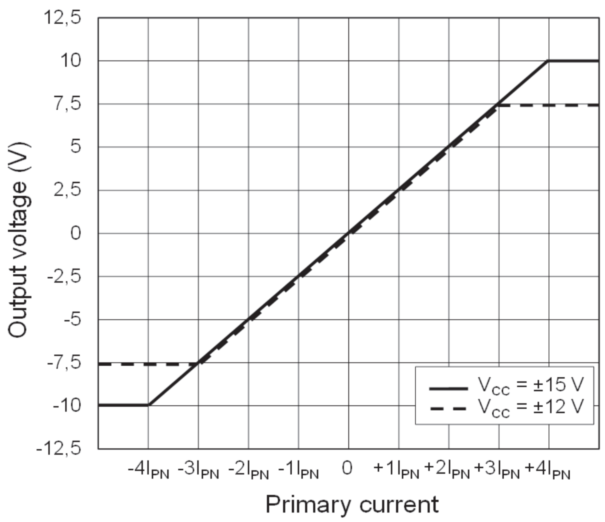


Fig. 1: Output voltage range for different supply voltages (SP3; SP10):

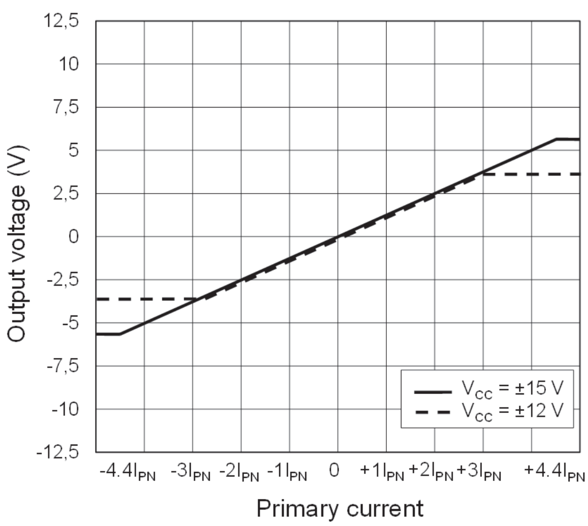


Fig. 2: Output voltage range for different supply voltages (SP7).

Electrical Data of SP3 and SP10

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_+	Positive supply voltage		+14.3	+15.0	+15.7	V
V_-	Negative supply voltage		-14.3	-15.0	-15.7	V
I_{PN}	Primary nominal current (RMS)		-	-	50	A
I_{PR}	Measuring range [1]		-200	-	+200	A
V_{outN}	Nominal output voltage (RMS)	$I_P = I_{PN}$, comp. Fig.1	-	2.5	-	V
R_M	Internal burden resistor for output signal		80	126	150	Ω
R_P	Resistance of primary conductor		-	0.1	0.15	mΩ
I_Q	Quiescent current	$I_P = 0$	-	19	25	mA
I_{CN}	Nominal current consumption	$I_P = I_{PN}$	-	37	50	mA
I_{CR}	Measuring range current consumption	$I_P = I_{PR}$	-	105	110	mA
I_{CM}	Maximal current consumption [2]	$I_P > I_{PR}$	-	-	120	mA

T_{amb} = 25 °C; V_{CC} = ±12 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_+	Positive supply voltage		+11.4	+12.0	+12.6	V
V_-	Negative supply voltage		-11.4	-12.0	-12.6	V
I_{PN}	Primary nominal current (RMS)		-	-	50	A
I_{PR}	Measuring range [1]		-150	-	+150	A
V_{outN}	Nominal output voltage (RMS)	$I_P = I_{PN}$, comp. Fig.1	-	2.5	-	V
R_M	Internal burden resistor for output signal		80	126	150	Ω
R_P	Resistance of primary conductor		-	0.1	0.15	mΩ
I_Q	Quiescent current	$I_P = 0$	-	19	25	mA
I_{CN}	Nominal current consumption	$I_P = I_{PN}$	-	37	50	mA
I_{CR}	Measuring range current consumption	$I_P = I_{PR}$	-	80	90	mA
I_{CM}	Maximal current consumption [2]	$I_P > I_{PR}$	-	-	95	mA

[1] For 3 s in a 60 s interval (RMS ≤ I_{PN}).

[2] Limited by output driver.

Electrical Data of SP7

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_+	Positive supply voltage		+14.3	+15.0	+15.7	V
V_-	Negative supply voltage		-14.3	-15.0	-15.7	V
I_{PN}	Primary nominal current (RMS)		-	-	50	A
I_{PR}	Measuring range [1]		-220	-	+220	A
V_{outN}	Nominal output voltage (RMS)	$I_P = I_{PN}$, comp. Fig.2	-	1.25	-	V
R_M	Internal burden resistor for output signal		-	63	75	Ω
R_P	Resistance of primary conductor			0.1	0.15	mΩ
I_Q	Quiescent current	$I_P = 0$	-	19	25	mA
I_{CN}	Nominal current consumption	$I_P = I_{PN}$	-	37	50	mA
I_{CR}	Measuring range current consumption	$I_P = I_{PR}$	-	105	110	mA
I_{CM}	Maximal current consumption [2]	$I_P > I_{PR}$	-	-	180	mA

T_{amb} = 25 °C; V_{CC} = ±12 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_+	Positive supply voltage		+11.4	+12.0	+12.6	V
V_-	Negative supply voltage		-11.4	-12.0	-12.6	V
I_{PN}	Primary nominal current (RMS)		-	-	50	A
I_{PR}	Measuring range [1]		-150	-	+150	A
V_{outN}	Nominal output voltage (RMS)	$I_P = I_{PN}$, comp. Fig.2	-	1.25	-	V
R_M	Internal burden resistor for output signal		-	63	75	Ω
R_P	Resistance of primary conductor			0.1	0.15	mΩ
I_Q	Quiescent current	$I_P = 0$	-	19	25	mA
I_{CN}	Nominal current consumption	$I_P = I_{PN}$	-	37	50	mA
I_{CR}	Measuring range current consumption	$I_P = I_{PR}$	-	80	90	mA
I_{CM}	Maximal current consumption [2]	$I_P > I_{PR}$	-	-	150	mA

[1] For 20 s in a 60 s interval (RMS ≤ I_{PN}).

[2] Limited by output driver.

Accuracy of SP3

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
ε_Σ	Accuracy [1] [2]	$I_P \leq I_{PN}$	-	±0.6	±0.8	% of I_{PN}
ε_G	Gain error [2]	$I_P \leq I_{PN}$	-	±0.5	±0.7	% of I_{PN}
ε_{off}	Offset error [2]	$I_P = 0$	-	±0.3	±0.8	% of I_{PN}
ε_{Lin}	Linearity error	$I_P \leq I_{PN}$; symmetrical current feed	-	±0.1	±0.15	% of I_{PN}
ε_{Hys}	Hysteresis	$4 \cdot I_{PN}$, Δt = 20 ms	-	-	0.04	% of I_{PN}
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 100Hz	-	-65	-	dB
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 15kHz	-	-	-23	dB
N_{RMS}	Noise level (RMS)	f ≤ 80 kHz	-	0.25	0.3	mV
N_{pk}	Noise level (peak)	f ≤ 80 kHz	-	2.2	3.0	mV

T_{amb} = (-25…+85)°C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$T\varepsilon_G$	Additional temperature induced gain error	$I_P \leq I_{PN}$	-	-	±0.5	% of I_{PN}
$T\varepsilon_{off}$	Additional temperature induced offset error	$I_P = 0$	-	-	±1.0	% of I_{PN}
$T\varepsilon_{Lin}$	Additional temperature induced linearity error	$I_P \leq I_{PN}$	-	-	±0.1	% of I_{PN}
$T\varepsilon_\Sigma$	Typical total accuracy [3]	$I_P \leq I_{PN}$	-	±1.5	-	% of I_{PN}

[1] Accuracy contains ε_G and ε_{Lin}.

[2] Does not include additional error of 0.5% (I_{PN}) due to aging.

[3] Typical total accuracy measured in temperature range (including error at T_{amb} = 25 °C).

Accuracy of SP10

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
ε_{Σ}	Accuracy [1) 2)]	$I_P \leq I_{PN}$	-	-	±0.5	% of I_{PN}
ε_G	Gain error [2)]	$I_P \leq I_{PN}$	-	-	±0.4	% of I_{PN}
ε_{off}	Offset error [2)]	$I_P = 0$	-	-	±0.2	% of I_{PN}
ε_{Lin}	Linearity error	$I_P \leq I_{PN}$; symmetrical current feed	-	±0.1	±0.15	% of I_{PN}
ε_{Hys}	Hysteresis	$4 \cdot I_{PN}$, Δt = 20 ms	-	-	0.04	% of I_{PN}
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 100Hz	-	-65	-	dB
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 15kHz	-	-	-23	dB
N_{RMS}	Noise level (RMS)	f ≤ 80 kHz	-	0.25	0.3	mV
N_{pk}	Noise level (peak)	f ≤ 80 kHz	-	2.2	3.0	mV

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$T\varepsilon_G$	Additional temperature induced gain error	$I_P \leq I_{PN}$	-	-	±0.5	% of I_{PN}
$T\varepsilon_{off}$	Additional temperature induced offset error	$I_P = 0$	-	-	±1.0	% of I_{PN}
$T\varepsilon_{Lin}$	Additional temperature induced linearity error	$I_P \leq I_{PN}$	-	-	±0.1	% of I_{PN}
$T\varepsilon_{\Sigma}$	Typical total accuracy [3)]	$I_P \leq I_{PN}$	-	±1.5	-	% of I_{PN}

1) Accuracy contains ε_G and ε_{Lin}.

2) Does not include additional error of 0.5% (I_{PN}) due to aging.

3) Typical total accuracy measured in temperature range (including error at T_{amb} = 25 °C).

Accuracy of SP7

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
ε_Σ	Accuracy [1] [2]	$I_P \leq I_{PN}$	-	±0.6	±0.8	% of I_{PN}
ε_G	Gain error [2]	$I_P \leq I_{PN}$	-	±0.5	±0.7	% of I_{PN}
ε_{off}	Offset error [2]	$I_P = 0$	-	±0.3	±0.8	% of I_{PN}
ε_{Lin}	Linearity error	$I_P \leq I_{PN}$; symmetrical current feed	-	±0.1	±0.2	% of I_{PN}
ε_{Hys}	Hysteresis	$4 \cdot I_{PN}$, Δt = 20 ms	-	-	0.04	% of I_{PN}
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 100Hz	-	-65	-	dB
PSRR	Power supply rejection rate	$f_{\Delta Vcc} \leq$ 15kHz	-	-	-30	dB
N_{RMS}	Noise level (RMS)	f ≤ 80 kHz	-	0.2	0.25	mV
N_{pk}	Noise level (peak)	f ≤ 80 kHz	-	2.0	2.5	mV

T_{amb} = 25 °C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$T\varepsilon_G$	Additional temperature induced gain error	$I_P \leq I_{PN}$	-	-	±0.5	% of I_{PN}
$T\varepsilon_{off}$	Additional temperature induced offset error	$I_P = 0$	-	-	±1.0	% of I_{PN}
$T\varepsilon_{Lin}$	Additional temperature induced linearity error	$I_P \leq I_{PN}$	-	-	±0.1	% of I_{PN}
$T\varepsilon_\Sigma$	Typical total accuracy [3]	$I_P \leq I_{PN}$	-	±1.5	-	% of I_{PN}

[1] Accuracy contains ε_G and ε_{Lin}.

[2] Does not include additional error of 0.5% (I_{PN}) due to aging.

[3] Typical total accuracy measured in temperature range (including error at T_{amb} = 25 °C).

General Data

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
T_{amb}	Ambient temperature [1]		-25	-	+85	°C
T_{stg}	Storage temperature		-25	-	+105	°C
T_B	Busbar temperature [1]		-25	-	+105	°C
T_{THT}	Solder temperature [2]	For 7 seconds	-	-	265	°C
m	Mass		-	6.5	6.7	g

Dynamic Data of SP3 and SP10

T_{amb} = 25°C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
t_{reac}	Reaction time [3]	10 % I_{PN} to 10 % $I_{out,N}$	-	0.13	0.2 [4]	µs
t_{rise}	Rise time [3]	10 % $I_{out,N}$ to 90 % $I_{out,N}$	-	0.6	1.7 [4]	µs
t_{resp}	Response time [3]	90 % I_{PN} to 90 % $I_{out,N}$	-	0.6	1.6 [4]	µs
f_{co}	Upper cut-off frequency	-3 dB	200	300	-	kHz
ΔV_{TR}	Transient output voltage	0 V to 530 V (3.7 kV/µs); see Fig. 3	-	0.045 [4]	0.085	V
t_{recTR}	Transient recovery time	0 V to 530 V (3.7 kV/µs); see Fig. 3	-	3.0	3.3 [4]	µs

Dynamic Data of SP7

T_{amb} = 25°C; V_{CC} = ±15 V; unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
t_{reac}	Reaction time [3]	10 % I_{PN} to 10 % $I_{out,N}$	-	0.09	0.15 [4]	µs
t_{rise}	Rise time [3]	10 % $I_{out,N}$ to 90 % $I_{out,N}$	-	0.35	0.7 [4]	µs
t_{resp}	Response time [3]	90 % I_{PN} to 90 % $I_{out,N}$	-	0.35	0.9 [4]	µs
f_{co}	Upper cut-off frequency	-3 dB	200	300	-	kHz
ΔV_{TR}	Transient output voltage	0 V to 530 V (3.7 kV/µs); see Fig. 3	-	0.03 [4]	0.06	V
t_{recTR}	Transient recovery time	0 V to 530 V (3.7 kV/µs); see Fig. 3	-	3.0	3.3 [4]	µs

[1] Operating condition.

[2] Depending on the size of the primary conductor, variation of pre-heating parameters (temperature, duration) might be necessary in order to ensure sufficient soldering results.

[3] $I_P = I_{PN}$, di/dt of 400 A/µs.

[4] With recommended RC output filter values according to page 13.

Isolation Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
V_I	Isolation test voltage (RMS)	50/60 Hz, 60 s	4.4	-	-	kV
V_{imp}	Impulse withstand voltage	1.2/50 µs	8.0	-	-	kV
d_{cp}	Creepage distance		6.3	-	-	mm
d_{cl}	Clearance distance [1)		6.3	-	-	mm
V_B	System voltage (RMS) [2)	Reinforced isolation PD2, CAT III	300	-	-	V
V_B'	System voltage (RMS) [2)	Basic isolation PD2, CAT III	600	-	-	V
ESD	Electro static test voltage	HBM, contact discharge method	-	8.0	-	kV

[1)] If mounted on a PCB, the minimal clearance distance might be reduced according to the PCB layout (e.g. diameter of drilling holes and annular rings).

[2)] According to DIN EN 50178, DIN EN 61800-5-1.

Typical Performance Characteristics of SP3 / SP10

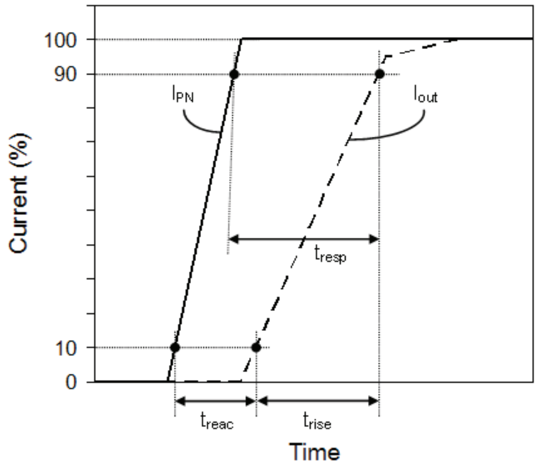


Fig. 3: Definition of reaction time (t_{reac}), rise time (t_{rise}) and response time (t_{resp}).

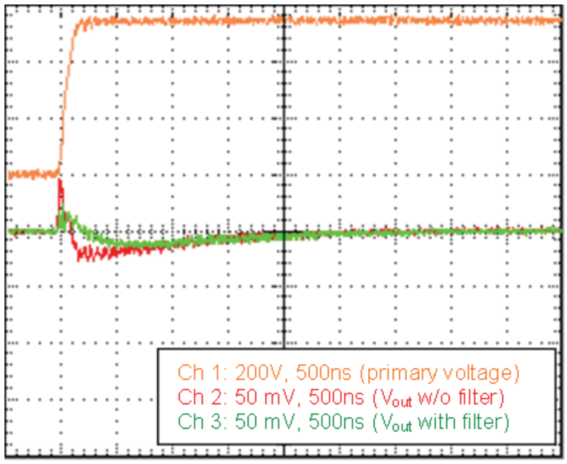


Fig. 4: dV/dt (3.7 kV/µs; 530 V voltage on primary conductor; filter configuration acc. to Tab. 1).

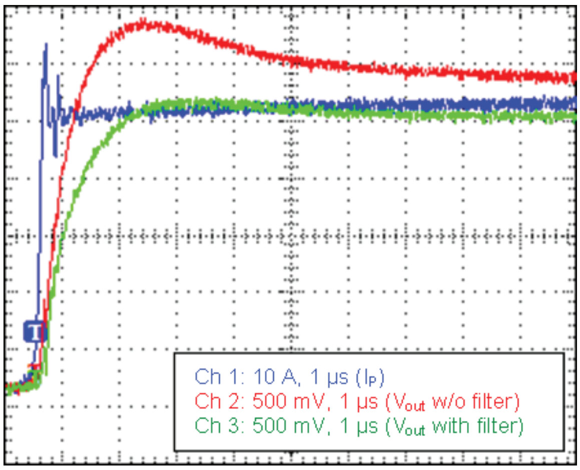


Fig. 5: Step response (I_P = 50 A; di/dt ≈ 400 A/µs; filter configuration acc. to Tab. 1).

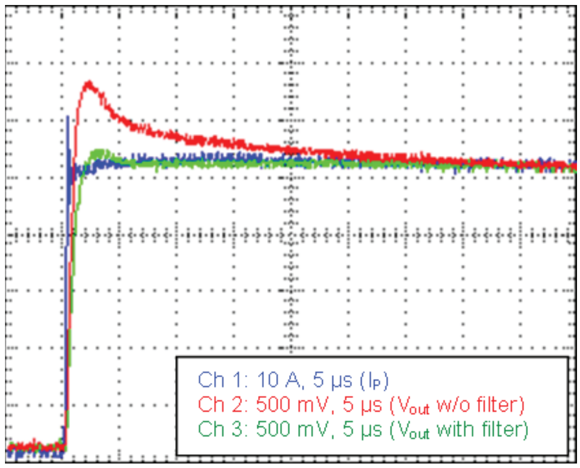


Fig. 6: Step response (IP = 50 A; di/dt ≈ 400 A/µs; filter configuration acc. to Tab. 1).

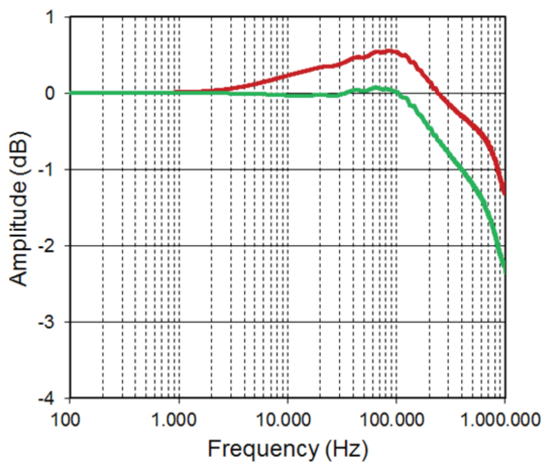


Fig. 7: Typical frequency response with RC-filter (green) and without (red). Filter configuration acc. to Tab. 1.

Typical Performance Characteristics of SP7

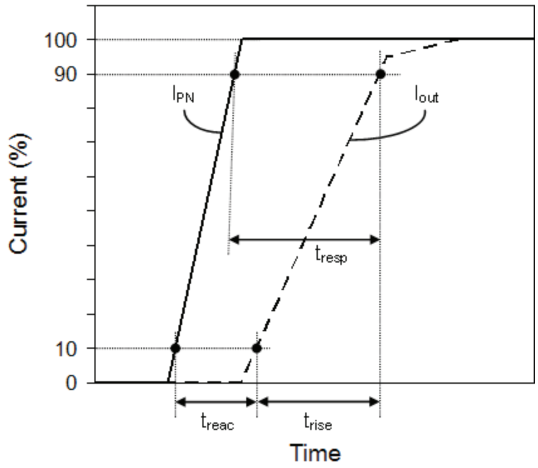


Fig. 8: Definition of reaction time (t_{reac}), rise time (t_{rise}) and response time (t_{resp}).

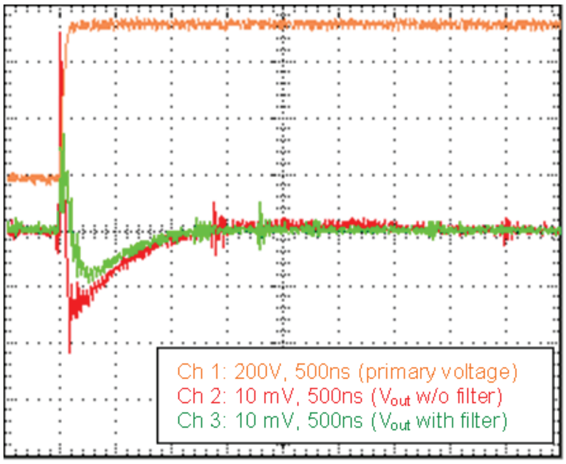


Fig. 9: dV/dt (3.7 kV/µs; 530 V voltage on primary conductor; filter configuration acc. to Tab. 1).

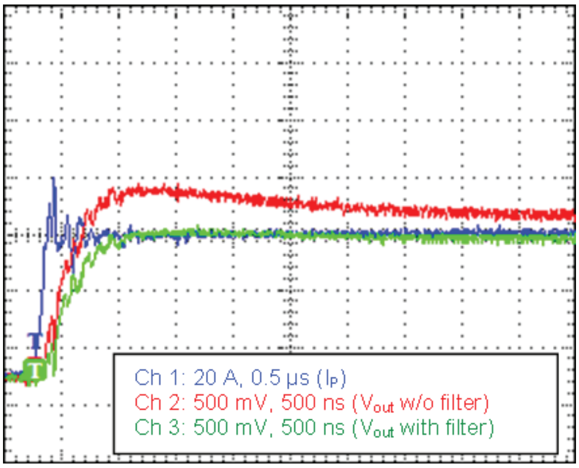


Fig. 10: Step response (I_P = 50 A; di/dt ≈ 400 A/µs; filter configuration acc. to Tab. 1).

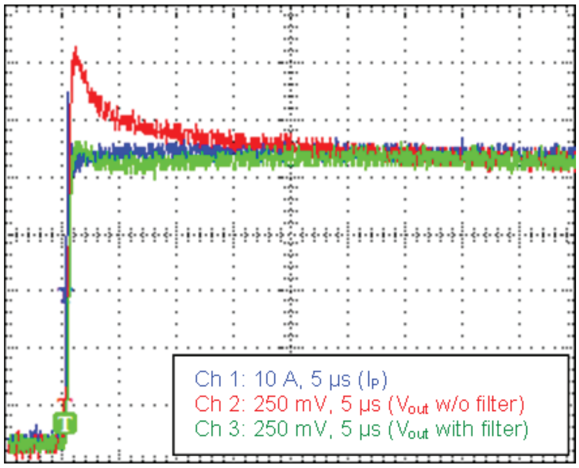


Fig. 11: Step response (IP = 50 A; di/dt ≈ 400 A/µs; filter configuration acc. to Tab. 1).

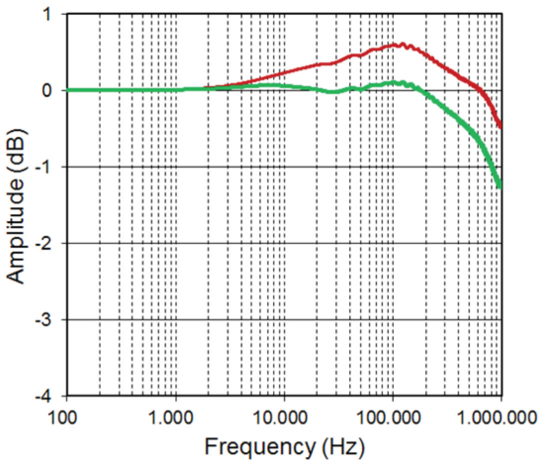


Fig. 12: Typical frequency response with RC-filter (green) and without (red). Filter configuration acc. to Tab. 1.

Pinning

Pad	Symbol	Parameter
1	V_+	Positive supply voltage
2	V_-	Negative supply voltage
3	GND	Ground
4	SGND	Signal ground
5	V_{out}	Signal output
6	I_{in}	Primary current input
7	I_{out}	Primary current output

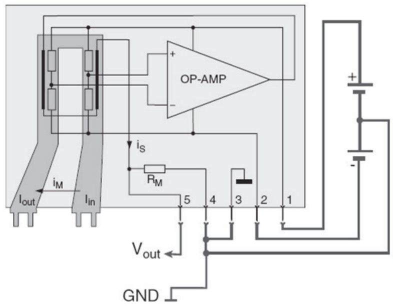
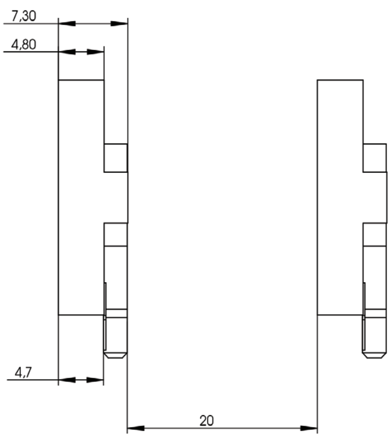
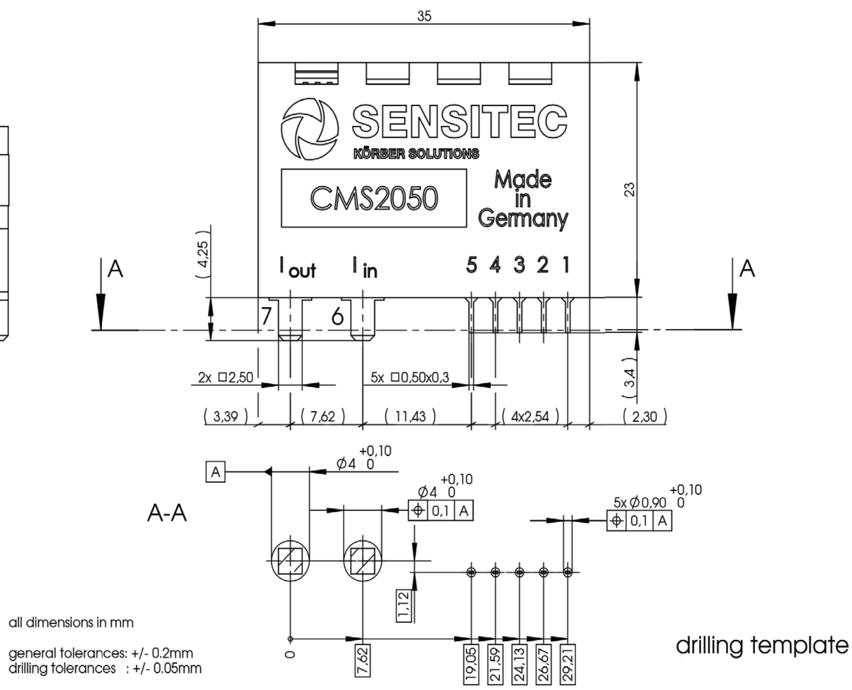


Fig. 13: Pinning of CMS2050.

Dimensions





Note:
Values given in brackets are not subject to general tolerances.

Fig. 14: Package outline.

Application Circuit

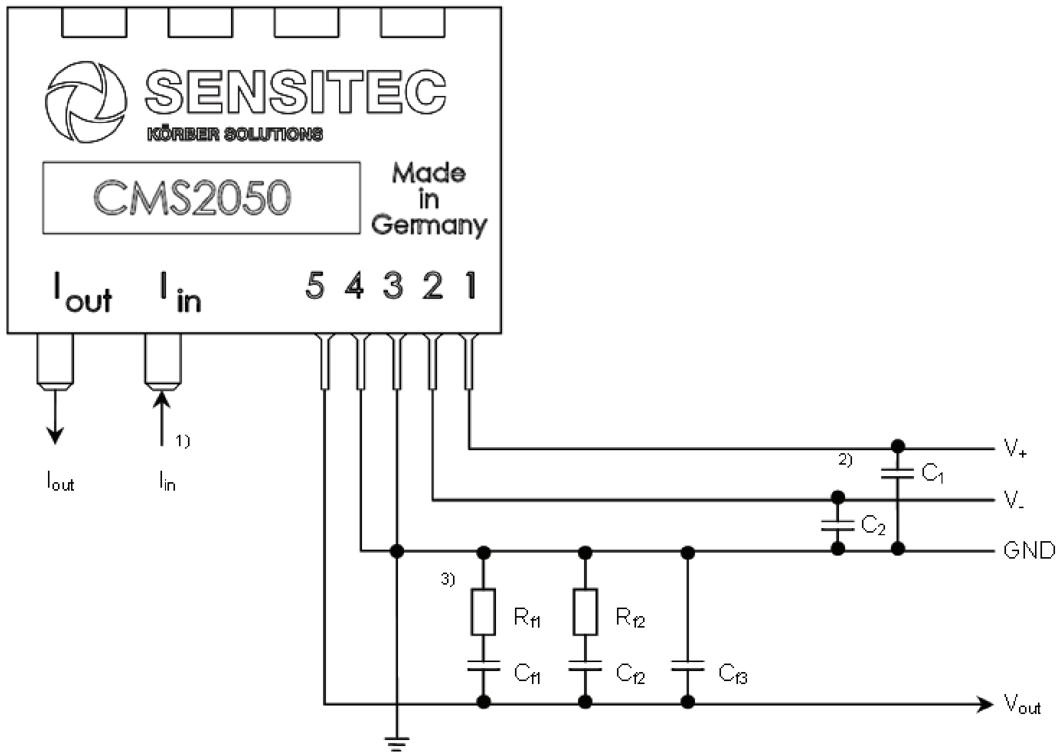


Fig. 15: Typical circuit to improve frequency response using a RC-filter network.

Filter Configuration

Recommended RC-filter values for di/dt ≈ 400 A/µs:

Type	R_{f1}	C_{f1}	R_{f2}	C_{f2}	C_{f3}
CMS2050-SP3 / -SP10	620 Ω	22 nF	-	-	3.3 nF
CMS2050-SP7	240 Ω	47 nF	-	-	3.3 nF

1) V_{out} is positive, if I_p flows from pin "I_{in}" to pin "I_{out}".

2) The power supply should always be buffered by 47 µF electrolytic capacitor C_1 and C_2.

3) To improve the frequency response, an RC-filter is recommended according to Tab.1. Depending on the application, further optimization is possible.

PCB Layout

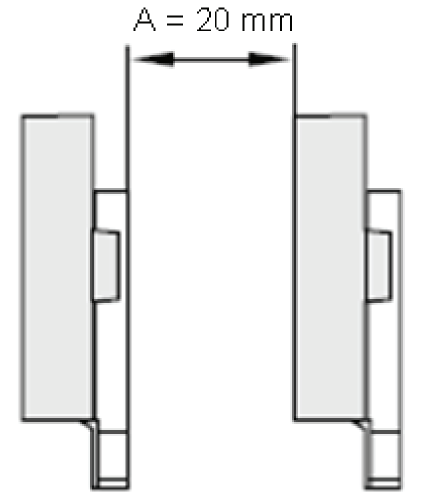


Fig. 16: Recommended clearance A among each other.

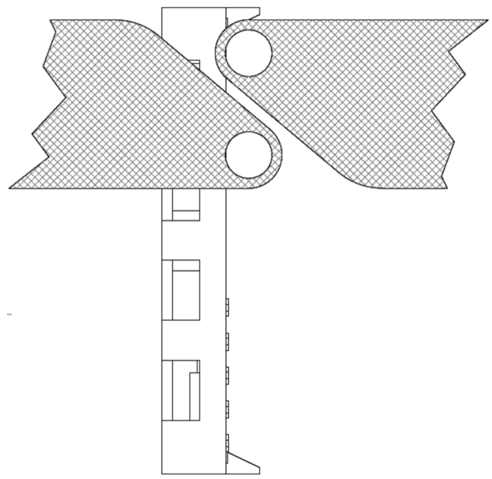


Fig. 17: Recommended current feed layout.

Additional Notes for the Designer

To operate the sensor within the specified accuracy, the following recommendations should be taken into account:

- In order to limit self-heating of the sensor and hence to not exceed the maximal allowed busbar temperature of 105°C, it is recommended to maximise the area of the current feeds on the PCB to provide a heat sink for the busbar. The required clearance and creepage distances need to be observed.
- The minimum clearance to other sources of magnetic fields (e.g. relays, motors, current conductors or permanent magnets) depends on the strength of the magnetic field. In order to keep the influence of magnetic stray fields on the current sensor signal below 1% (of IPN), both homogeneous magnetic fields and magnetic field gradients at the position of the sensor chip (located at the centre of the primary conductor) should be below 1 kA/m and 15 (A/m)/mm (18.7 µT/mm), respectively. Generally, shielding is possible to avoid influence of magnetic stray fields.

  Example: A conductor carrying 1 A generates a magnetic field of 20 A/m and a magnetic field gradient of 2.5 (A/m)/mm at a distance of 8 mm.

- For multiple sensor arrangements, it is recommended to place the sensors including their current feeds with a clearance (A) of at least 20mm to each other as shown in Fig. 16. A smaller distance may cause cross talk to adjacent sensors. The primary current feeds in the PCB may not to be routed underneath a sensor.
- Parts made of electrically conductive material (e.g. housing parts made of aluminium) placed in close proximity to the sensor may affect the dynamic sensor behaviour due to the induced eddy currents in these parts.
- Parts made of ferromagnetic material (e.g. housing parts made of steel) placed in close proximity to the sensor may affect the sensor’s accuracy as the magnetic field generated by the sensor’s primary conductor may be disturbed.

The CMS2000 Product Family

The CMS2005 is a member of the CMS2000 product family offering PCB-mountable THT current sensors from 5 A up to 100 A nominal current for various industrial applications.

	CMS2005	CMS2015	CMS2025	CMS2050	CMS2100
					
I_{PN} [1)]	5 A	15 A	25 A	50 A	100 A
I_{PR} [2)]	20 A	60 A	100 A	200 A	400 A

The CMK2000 demoboard offers the opportunity to learn the features and benefits of the CMS2000 current sensors in a quick an simple manner.

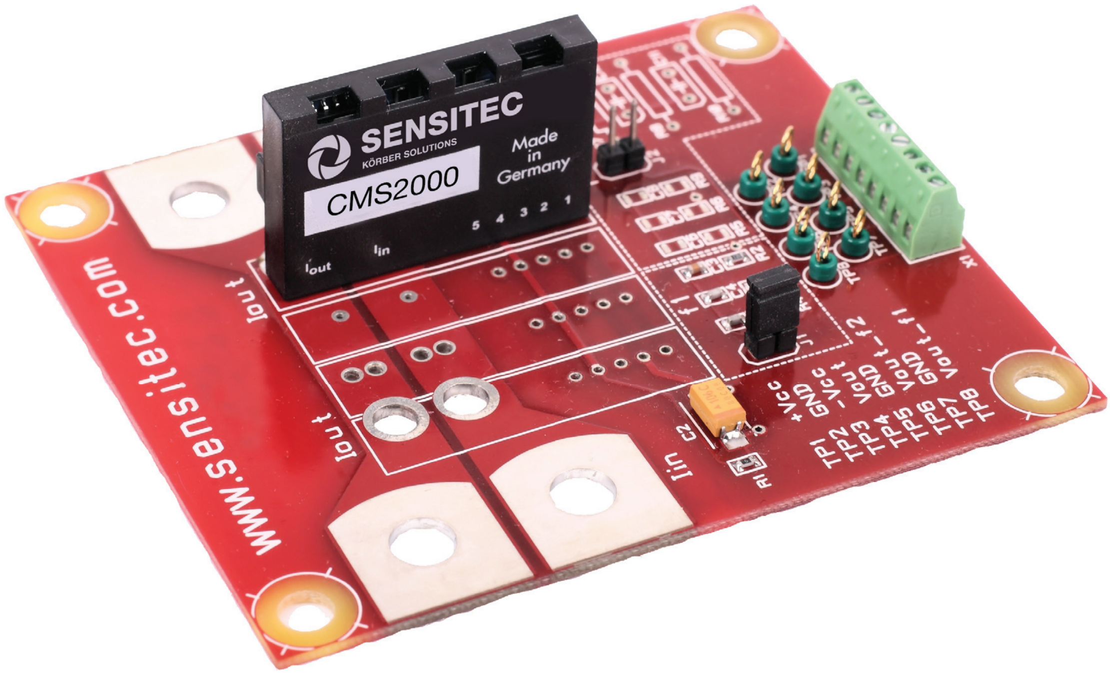


Fig. 18: The CMK2000 demoboards are available for different current ranges.

[1)] Nominal primary current (RMS).

[2)] Measurement range.

Safety Notes

⚠	**Warning!** This sensor shall be used in electric and electronic devices according to applicable standards and safety requirements. Sensitec's datasheet and handling instructions must be complied with. Handling instructions for current sensors are available at www.sensitec.com.
⚠	**Caution! Risk of electric shock!** When operating the sensor, certain parts, e. g. the primary busbar or the power supply, may carry hazardous voltage. Ignoring this warning may lead to serious injuries! Conducting parts of the sensor shall not be accessible after installation.

General Information

Product Status

Article	Status
CMS2050	The product is in series production.
Note	The status of the product may have changed since this data sheet was published. he latest information is available on the internet at www.sensitec.com.

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Life Critical Applications

These products are not qualified for use in life support appliances, aeronautical applications or devices or systems where malfunction of these products can reasonably be expected to result in personal injury.

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